TOSHIBA THYRISTOR SILICON PLANAR TYPE

USF05G49

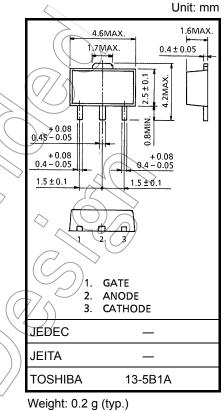
LOW POWER SWITCHING AND CONTROL **APPLICATIONS**

• Repetitive Peak Off-State Voltage : VDRM = 400 V Repetitive Peak Reverse Voltage $: V_{RRM} = 400 \text{ V}$ • Average On-State Current $I_{T(AV)} = 500 \text{ mA}$

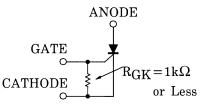
MAXIMUM RATINGS

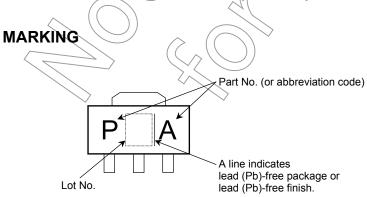
CHARACTERISTIC	SYMBOL	RATING	UMIT
Repetitive Peak Off-State Voltage and Repetitive Peak Reverse Voltage	V _{DRM} V _{RRM}	400	
Non-Repetitive Peak Reverse Voltage (Non-Repetitive<5ms, $T_j = 0\sim125$ °C)	V _{RSM}	500)>>>
Average On-State Current (Half Sine Waveform)	I _{T (AV)}	500	> mA
R.M.S On-State Current	I _{T (RMS)}	800	mA
Peak One Cycle Surge On-State Current (Non-Repetitive)	I _{TSM}	9 (50Hz) 10 (60Hz)	A
I ² t Limit Value	I ² t(0.4	A ² s
Critical Rate of Rise of On-State Current (Note 1)	di / dt	10	A/µs
Peak Gate Power Dissipation	RGM	0.1	7/w
Average Gate Power Dissipation	P _G (AV)	0.01	A
Peak Forward Gate Voltage	V⊭GM	3.5	\searrow_{V}
Peak Reverse Gate Voltage	V _{RGM} <	(5/)	V
Peak Forward Gate Current	I _{GM}	125	mA
Junction Temperature	T	-40~125	°C
Storage Temperature Range	T _{stg}	-40~125	°C

Note 1: di / dt Test condition: i_G = 5mA, t_{gw} = 10µs, t_{gr}≤250ns



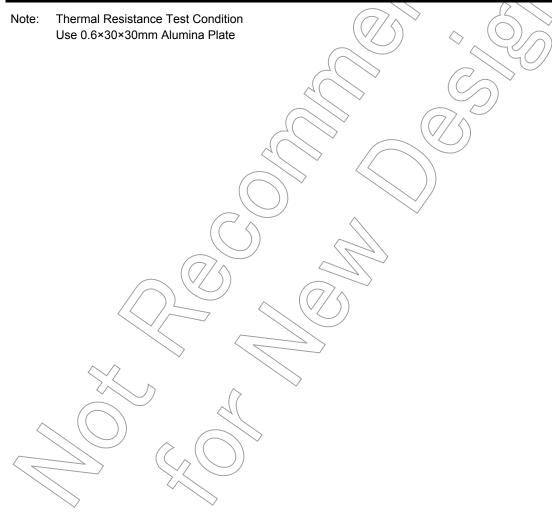
Note: Should be used with gate resistance as shown below.

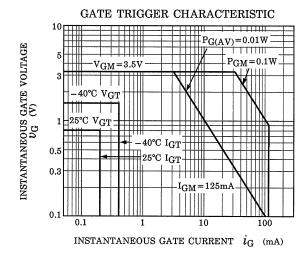


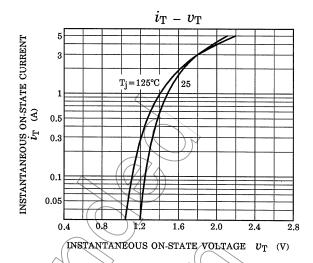


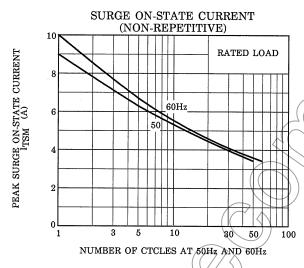
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

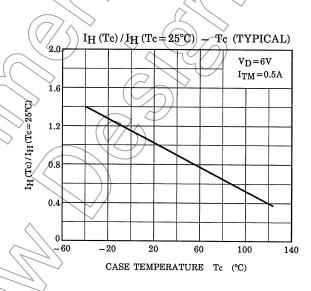
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current and Repetitive Peak Reverse Current	I _{DRM} I _{RRM}	V _{DRM} = V _{RRM} = Rated	_	_	10	μА
Peak On-State Voltage	V_{TM}	I _{TM} = 1A	_	_	1.5	V
Gate Trigger Voltage	V _{GT}	$V_D = 6V, R_L = 100\Omega$		_	0.8	V
Gate Trigger Current	I _{GT}	$R_{GK} = 1k\Omega$	() >-	200	μΑ
Holding Current	IH	I_{TM} = 500mA, V_D = 6V R _{GK} = 1k Ω	7	_	6	mA
Critical Rate of Rise of Off-State Voltage	d _V / dt	V _{DRM} = Rated, R _{GK} = 1kΩ Exponential Rise	<u> </u>	200	_	V / µs
Gate Turn-On Time	tgt	V_D = Rated, i_G = 5mA R _{GK} = 1k Ω	_		1.5	μs
Thermal Resistance	R _{th(j−a)}	Junction to Ambient	_	4	70	°C/W

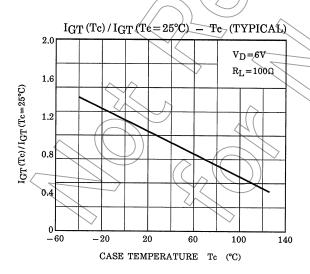


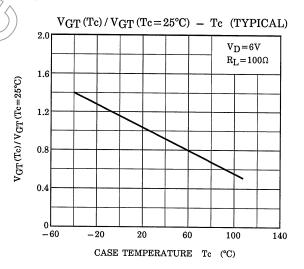


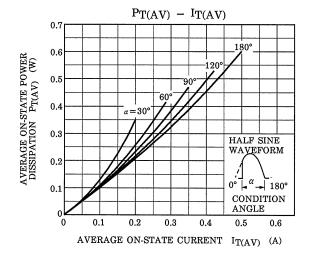


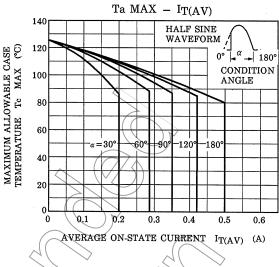


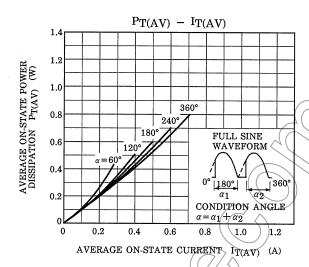


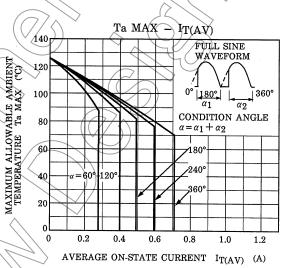


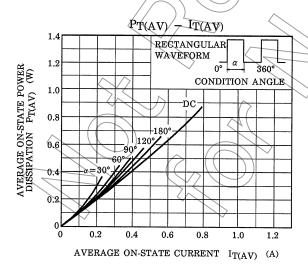


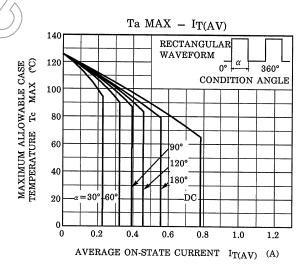




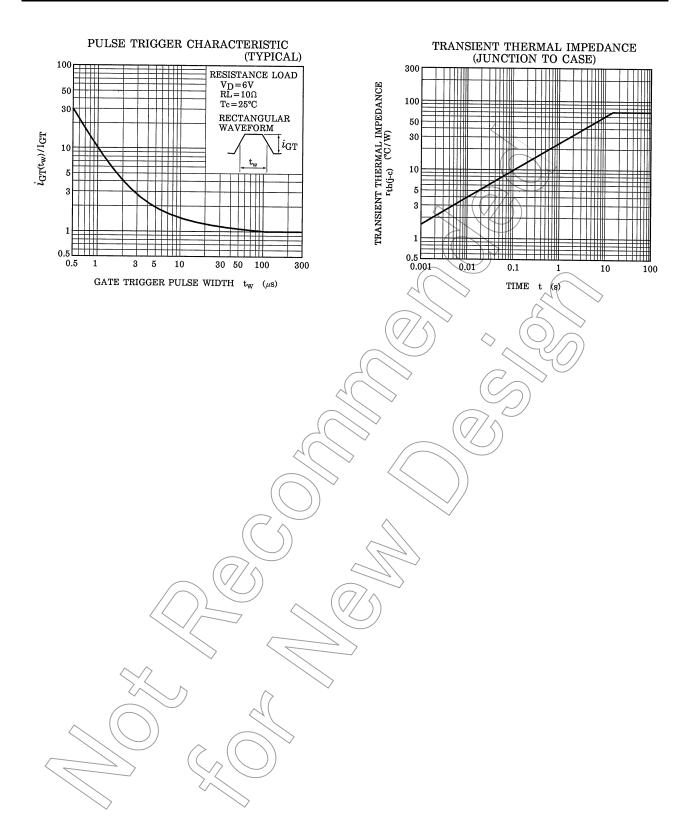








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2004-07-06